#### PJD50N04-AU **40V N-Channel Enhancement Mode MOSFET** 40 V Current 50 A Voltage Features R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V, I<sub>D</sub>@8A<9.5mΩ</li> • $R_{DS(ON)}$ , $V_{GS}$ @4.5V, $I_D$ @4A<14m $\Omega$ TO-252AA • High switching speed • Improved dv/dt capability • Low Gate Charge Drain • Low reverse transfer capacitance • AEC-Q101 qualified Gate \_ • Lead free in compliance with EU RoHS 2.0 • Green molding compound as per IEC 61249 standard Source **Mechanical Data** • Case : TO-252AA Package

- Terminals : Solderable per MIL-STD-750, Method 2026
- Weight : 0.0104 ounces, 0.297grams

### **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	40	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	v	
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C	I <sub>D</sub>	50		
	$T_{\rm C}=100^{\circ}{\rm C}$		31	А	
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	100		
Power Dissipation	T <sub>C</sub> =25°C	PD	64.9	W	
	T <sub>C</sub> =100°C		32.5	vv	
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C	I <sub>D</sub>	9.6	٨	
	T <sub>A</sub> =70°C		7.7	A	
Power Dissipation	T <sub>A</sub> =25°C	PD	2.4	14/	
	T <sub>A</sub> =70°C		1.6	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	2.31	°C/W	
	Junction to Ambient	$R_{\thetaJA}$	62.5		

Limited only By Maximum Junction Temperature



# PJD50N04-AU

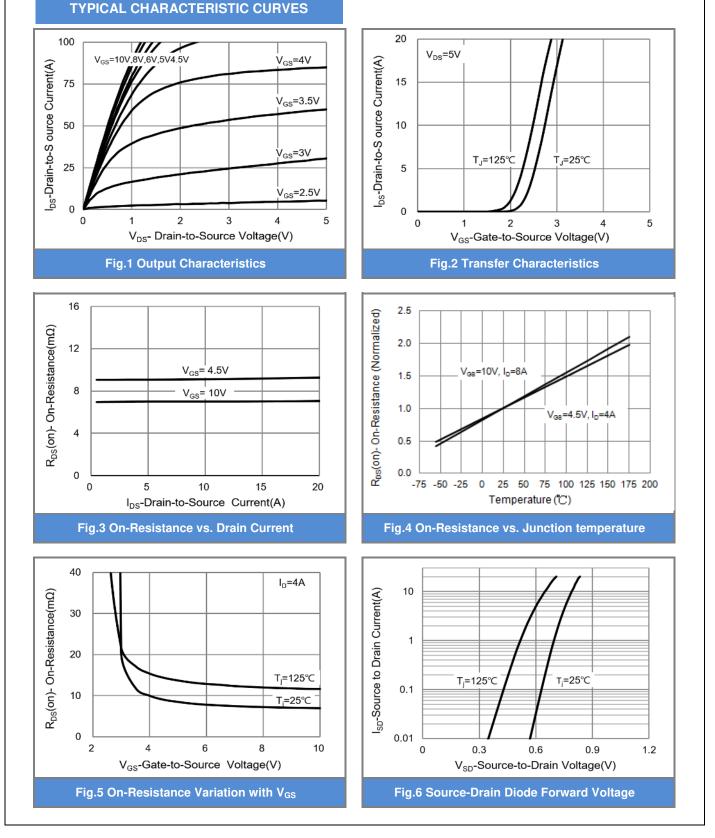
## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>		40	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>		1	1.7	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =10V, $I_{D}$ =8A	-	8	9.5	mΩ
		$V_{GS}$ =4.5V, $I_{D}$ =4A	-	11	14	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =40V, $V_{GS}$ =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)		·				
Total Gate Charge	Qg	V <sub>DS</sub> =20V, I <sub>D</sub> =8A, V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	22	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	4.2	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	4.0	-	
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHZ	-	1258	-	pF
Output Capacitance	Coss		-	134	-	
Reverse Transfer Capacitance	Crss		-	88	-	
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DS</sub> =15V, I <sub>D</sub> =1A, V <sub>GS</sub> =10V, R <sub>G</sub> =3.3Ω (Note 2,3)	-	13	-	ns
Turn-On Rise Time	tr		-	14	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	45	-	
Turn-Off Fall Time	t <sub>f</sub>	(	-	9	-	
Drain-Source Diode	·	·				
Maximum Continuous Drain-Source			-	-	50	А
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.7	1	V

NOTES :

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150$  °C. Ratings are based on low frequency and duty cycles to keep initial  $T_J = 25$  °C.
- 4. The maximum current rating is package limited.
- 5.  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

March 28,2019-REV.00

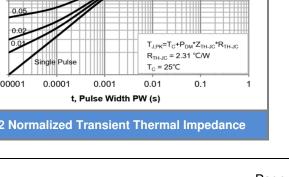


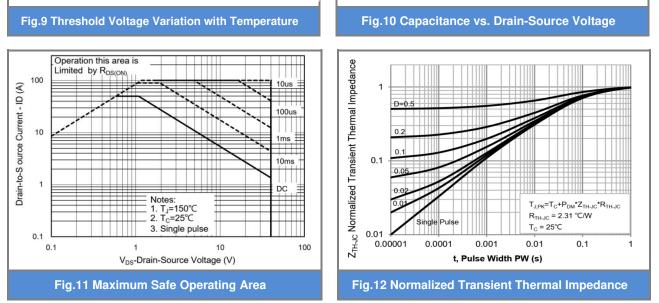
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2000

1500

1000

500

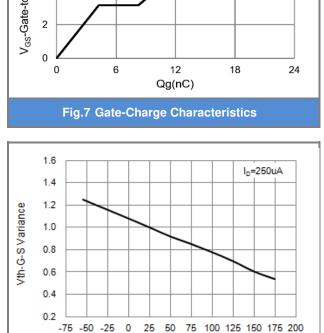
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0

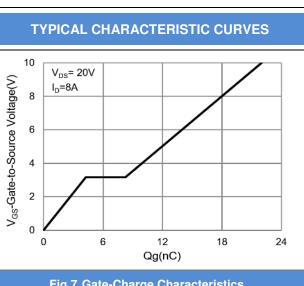
Crss

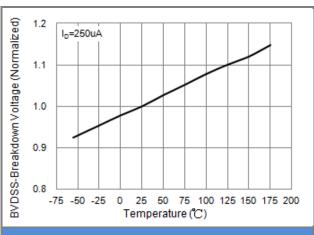
10

Capacitance (pF)



Temperature (°C)







Ciss

Coss

20

V<sub>DS</sub>-Drain-Source Voltage (V)

30

40

 $V_{GS} = 0V$ 

f = 1MHz

PANJ SEM CONDUCTOR PJD50N04-AU



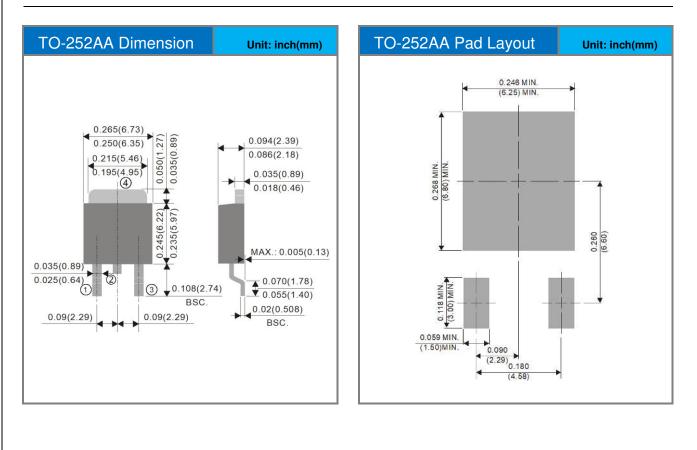


## PJD50N04-AU

### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Packing Type Marking	
PJD50N04-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D50N04	Halogen free

### **Packaging Information & Mounting Pad Layout**





# PJD50N04-AU

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